NSN 5962-01-115-6148

Memory Microcircuit - Page 1 of 1



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Body Length:	
0.925 inches	
Body Width:	
0.302 inches	
Body Height:	
0.175 inches	
Maximum Power Dissi	pation Rating:
409.6 milliwatts	
Operating Tempuratur	e Range:
+0.0/+75.0 degrees cels	sius
Storage Tempurature I	Range:
-65.0/+150.0 degrees ce	elsius
Features Provided:	
Hermetically sealed and	programmable and bipolar and 3-state output and w/enable
Inclosure Material:	
Ceramic	
Inclosure Configuratio	n:
Dual-in-line	
Output Logic Form:	
Transistor-transistor logi	ic
Input Circuit Pattern:	
12 input	
Voltage Rating And Ty	vpe Per Characteristic:
7.0 volts total supply	
Time Rating Per Chact	teristic:
40.00 nanoseconds pro	ppagation delay time, low to high level output and 40.00 nanoseconds propagation delay time, high to low level
output	
Memory Device Type:	
Prom	
Memory Capacity:	
Unknown	
Terminal Type And Qu	iantity:
18 printed circuit	
Shelf Life:	
N/a	
Unit Of Measure:	
Demilitarization:	
Yes - demil/mli	
Fiig:	
A458a0	